

### PNT523T503E0-2

## High EB High DC gain Ultra-Small package switch transistor

### **Feature**

This device is Pb-Free, Halogen Free/BFR Free and RoHS compliant.

Package: SOT-523

> Emitter -Base Breakdown Voltage 11V

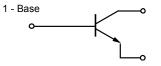
> High DC current gain typical 380

Low Saturation Voltage 80mv

> 0.15 continuous collector current

> NPN switch transistor

3 - Collector



2 - Emitter

#### **Mechanical Characteristics**

Lead finish:100% matte Sn(Tin)

Mounting position: Any

➤ Qualified max reflow temperature:260°C

Device meets MSL 1 requirements

➤ Pure tin plating: 7 ~ 17 um

Pin flatness:≤3mil

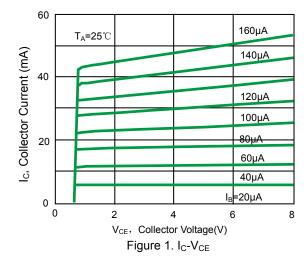
## Electrical characteristics per line@25℃( unless otherwise specified)

Parameter	Symbol	Value	Units
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	50	V
Collector-Base Breakdown Voltage	V (BR)CBO	80	V
Emitter -Base Breakdown Voltage	V (BR)EBO	11	V
Collector Current	Ic	0.15	А
Total Dissipation @25°C	P <sub>tot</sub>	0.15	W
Storage Temperature	T <sub>stg</sub>	-65~150	°C
Max. Operating Junction Temperature	Tj	150	°C

### Absolute maximum rating@25℃

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	I <sub>C</sub> =50uA	80			V
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	I <sub>C</sub> =1mA	50			V
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	I <sub>E</sub> =50uA		11		V
Collector Cut-off Current (I <sub>E</sub> =0)	I <sub>CBO</sub>	V <sub>CB</sub> =60V			0.1	μΑ
Emitter Cut-off Current(I <sub>C</sub> =0)	I <sub>EBO</sub>	V <sub>EB</sub> =7V			0.1	μΑ
DC Current Gain	h <sub>FE</sub>	I <sub>C</sub> =1mA,V <sub>CE</sub> =6V	250		560	-
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =50mA,I <sub>B</sub> =5mA	-	0.08		V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =12V,I <sub>E</sub> =-2mA,f=100MHz		200		MHz
Output Capacitance	Cob	V <sub>CE</sub> =12V,I <sub>E</sub> =0mA,f=1MHz		2	3.5	pF

## **Typical Characteristics**



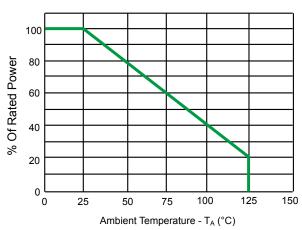
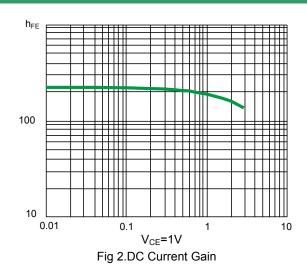


Fig3. Power Derating Curve



0.1 0.01 0.01 0.01 0.1 1 10 hFE=100 I<sub>c</sub>(A)

Fig 4.Collector-Emitter Saturation Voltage

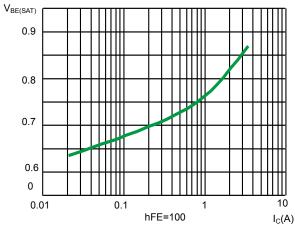
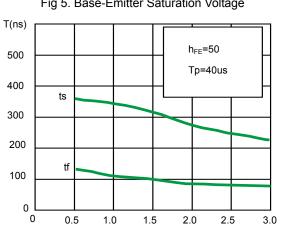


Fig 5. Base-Emitter Saturation Voltage



h<sub>FE</sub>=100 Fig 7. Switching Times Resistive Load

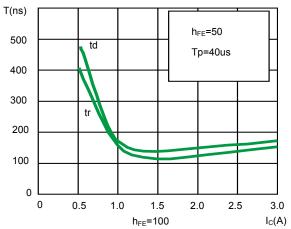
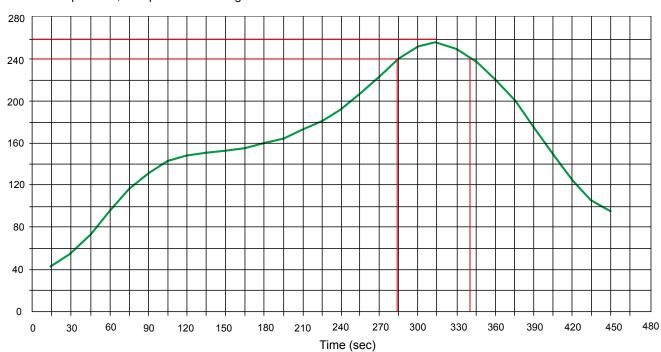


Fig 6.Switching Times Resistive Load

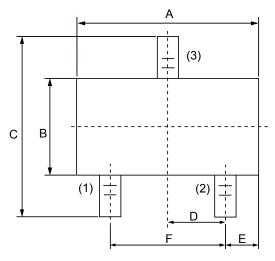
### **Solder Reflow Recommendation**

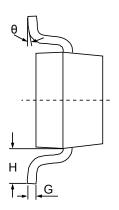
Peak Temp=257℃, Ramp Rate=0.802deg. ℃/sec

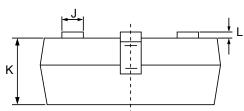


 $I_{C}(A)$ 

## Product dimension (SOT-523)



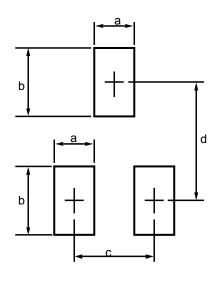




Dim	Millimeters		Inches		
Dim	MIN	MAX	MIN	MAX	
А	1.50	1.70	0.059	0.067	
В	0.75	0.85	0.030	0.033	
С	1.450	1.750	0.057	0.069	
D	0.50BSC		0.020BSC		
Е	0.30	0.33	0.012	0.015	
F	0.900	1.100	0.035	0.043	
G	0.100	0.200	0.004	0.008	
Н	0.550		0.0	)22	
J	0.150	0.250	0.006	0.010	
К	0.700	0.900	0.028	0.038	
L	0.024	0.027	0.600	0.700	
θ	0°	4°	0°	4°	

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Dim	Millimeters		
	MIN	MAX	
а		0.4	
b		0.6	
С		1.0	
d		1.24	

## Ordering information

Device	Package	Shipping
PNT523T503E0-2	SOT-523 (Pb-Free)	3000 / Tape & Reel

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